## 三元系 Si クラスレート K<sub>8</sub>Al<sub>7</sub>Si<sub>39</sub> の合成と物性

Synthesis and Physical properties of ternary Clathrate K<sub>8</sub>Al<sub>7</sub>Si<sub>39</sub>

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Earth abundant and non-toxic elements based functional materials have been found commercially viable for applications. Pursuing this, ternary phase clathrate  $K_8Al_7Si_{39}$  was synthesized and its physical properties were studied. X-ray diffraction, induction-coupled plasma optical emission spectroscopy (*ICP-OES*), and electron probe micro-analysis have revealed that the synthesized compound is a type-I ternary clathrate  $K_8Al_7Si_{39}$  with lattice parameter a = 10.434(1) Å. Chemical composition of as-synthesized sample, determined by *ICP-OES*, was 14.7(2) at.% K, 13.2(1) at.% Al, and 72.1(7) at.% Si, which expresses its chemical formula  $K_{7.9(2)}Al_{7.1(1)}Si_{38.9(4)}$ . Low temperature (10-320K) transport measurements were performed on the compound. Electrical resistivity measurements suggested that it has metallic nature. Moderate value of Seebeck coefficient with *n*-type conduction was observed. Hall measurement confirmed *n*-type carriers with almost constant concentration (*n*) of  $8.8\sim14.5*10^{20}$  cm<sup>-3</sup> and mobility ( $\mu$ ) of  $4.5\sim10.3$  cm<sup>2</sup>V<sup>-1</sup>s<sup>-1</sup> in the range 10-300K. Slight decrease in thermal conduction was observed with increasing temperature, after a maximum at  $\sim50$ K, indicating metallic type thermal conduction.